Low-Voltage CMOS Octal Transceiver

With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX245 is a high performance, non–inverting octal transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A VI specification of 5.5V allows MC74LCX245 inputs to be safely driven from 5V devices. The MC74LCX245 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24mA at both A and B ports. The Transmit/Receive (T/R) input determines the direction of data flow through the bi–directional transceiver. Transmit (active–HIGH) enables data from A ports to B ports; Receive (active–LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V VCC Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- · Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

MC74LCX245



LOW-VOLTAGE CMOS OCTAL TRANSCEIVER



DW SUFFIX PLASTIC SOIC CASE 751D-04



M SUFFIX
PLASTIC SOIC EIAJ
CASE 967-01

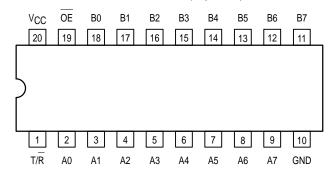


SD SUFFIX PLASTIC SSOP CASE 940C-03



DT SUFFIXPLASTIC TSSOP
CASE 948E-02

Pinout: 20-Lead (Top View)

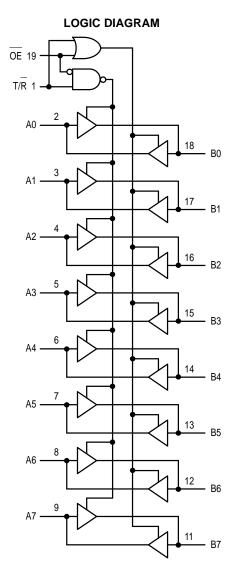


PIN NAMES

| Pins | Function |
|-----------|---|
| OE T/R | Output Enable Input Transmit/Receive Input |
| A0–A7 | Side A 3–State Inputs or 3–State Outputs |
| B0-B7 | Side B 3–State Inputs or 3–State Outputs |



REV 3



| INF | PUTS | OPERATING MODE | |
|-----|------|-----------------|--|
| OE | T/R | Non-Inverting | |
| L | L | B Data to A Bus | |
| L | Н | A Data to B Bus | |
| Н | Х | Z | |

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; For I_{CC} reasons, Do Not Float Inputs

ABSOLUTE MAXIMUM RATINGS*

| Symbol | Parameter | Value | Condition | Unit |
|------------------|----------------------------------|-----------------------------------|----------------------|------|
| VCC | DC Supply Voltage | -0.5 to +7.0 | | V |
| VI | DC Input Voltage | -0.5 ≤ V _I ≤ +7.0 | | V |
| VO | DC Output Voltage | $-0.5 \le V_{O} \le +7.0$ | Output in 3-State | V |
| | | $-0.5 \le V_{O} \le V_{CC} + 0.5$ | Note 1. | V |
| lık | DC Input Diode Current | -50 | V _I < GND | mA |
| loк | DC Output Diode Current | -50 | V _O < GND | mA |
| | | +50 | VO > VCC | mA |
| Io | DC Output Source/Sink Current | ±50 | | mA |
| Icc | DC Supply Current Per Supply Pin | ±100 | | mA |
| ^I GND | DC Ground Current Per Ground Pin | ±100 | | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | | °C |

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied.

1. Output in HIGH or LOW State. Io absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Тур | Max | Unit |
|--------|---|------------|------------|------------------------|------|
| VCC | Supply Voltage Operating Data Retention Only | 2.0 1.5 | 3.3 3.3 | 3.6 3.6 | V |
| VI | Input Voltage | 0 | | 5.5 | V |
| VO | Output Voltage (HIGH or LOW State) (3–State) | 0 0 | | V _{CC} 5.5 | V |
| ЮН | HIGH Level Output Current, V _{CC} = 3.0V – 3.6V | | | -24 | mA |
| loL | LOW Level Output Current, V _{CC} = 3.0V – 3.6V | | | 24 | mA |
| IOH | HIGH Level Output Current, V _{CC} = 2.7V – 3.0V | | | -12 | mA |
| loL | LOW Level Output Current, V _{CC} = 2.7V – 3.0V | | | 12 | mA |
| TA | Operating Free-Air Temperature | -40 | | +85 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate, V_{IN} from 0.8V to 2.0V, $V_{CC} = 3.0V$ | 0 | | 10 | ns/V |

DC ELECTRICAL CHARACTERISTICS

| | | | T _A = -40°C | to +85°C | |
|-----------------|------------------------------------|--|------------------------|----------|------|
| Symbol | Characteristic | Condition | Min | Max | Unit |
| VIH | HIGH Level Input Voltage (Note 2.) | 2.7V ≤ V _{CC} ≤ 3.6V | 2.0 | | V |
| V _{IL} | LOW Level Input Voltage (Note 2.) | 2.7V ≤ V _{CC} ≤ 3.6V | | 0.8 | V |
| Vон | HIGH Level Output Voltage | $2.7V \le V_{CC} \le 3.6V; I_{OH} = -100\mu A$ | V _{CC} - 0.2 | | V |
| | | $V_{CC} = 2.7V; I_{OH} = -12mA$ | 2.2 | | |
| | | $V_{CC} = 3.0V; I_{OH} = -18mA$ | 2.4 | | |
| | | $V_{CC} = 3.0V; I_{OH} = -24mA$ | 2.2 | | |
| VOL | LOW Level Output Voltage | $2.7V \le V_{CC} \le 3.6V; I_{OL} = 100\mu A$ | | 0.2 | V |
| | | $V_{CC} = 2.7V; I_{OL} = 12mA$ | | 0.4 |] |
| | | V _{CC} = 3.0V; I _{OL} = 16mA | | 0.4 | |
| | | V _{CC} = 3.0V; I _{OL} = 24mA | | 0.55 | |

^{2.} These values of V_I are used to test DC electrical characteristics only.

MC74LCX245

DC ELECTRICAL CHARACTERISTICS (continued)

| | | | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | | |
|----------------|---------------------------------------|--|---|------|------|
| Symbol | Characteristic | Condition | Min | Max | Unit |
| l _l | Input Leakage Current | $2.7V \le V_{CC} \le 3.6V; 0V \le V_{I} \le 5.5V$ | | ±5.0 | μΑ |
| loz | 3–State Output Current | $2.7 \le V_{CC} \le 3.6V$; $0V \le V_O \le 5.5V$; $V_I = V_{IH}$ or V_{IL} | | ±5.0 | μΑ |
| lOFF | Power-Off Leakage Current | $V_{CC} = 0V$; V_I or $V_O = 5.5V$ | | 10 | μΑ |
| Icc | Quiescent Supply Current | $2.7 \le V_{CC} \le 3.6V$; $V_I = GND$ or V_{CC} | | 10 | μΑ |
| | | $2.7 \le V_{CC} \le 3.6V$; $3.6 \le V_I$ or $V_O \le 5.5V$ | | ±10 | μΑ |
| ΔlCC | Increase in I _{CC} per Input | $2.7 \le V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$ | | 500 | μΑ |

AC CHARACTERISTICS ($t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$)

| | | | | Limits | | |
|--|--|----------|-----------------------|----------------|------------------------|------|
| | | | T, | λ = −40°C to - | +85°C | |
| | | | V _{CC} = 3.0 | OV to 3.6V | V _{CC} = 2.7V | 1 |
| Symbol | Parameter | Waveform | Min | Max | Max | Unit |
| tPLH tPHL | Propagation Delay Input to Output | 1 | 1.5 1.5 | 7.0 7.0 | 8.0 8.0 | ns |
| ^t PZH ^t PZL | Output Enable Time to High and Low Level | 2 | 1.5 1.5 | 8.5 8.5 | 9.5 9.5 | ns |
| ^t PHZ ^t PLZ | Output Disable Time From High and Low Level | 2 | 1.5 1.5 | 7.5 7.5 | 8.5 8.5 | ns |
| ^t OSHL ^t OSLH | Output-to-Output Skew (Note 3.) | | | 1.0 1.0 | | ns |

^{3.} Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toshL) or LOW-to-HIGH (toslh); parameter guaranteed by design.

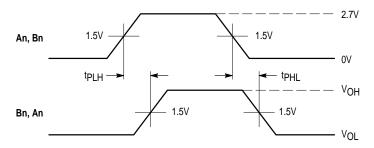
DYNAMIC SWITCHING CHARACTERISTICS

| | | | T _A = +25°C | | | |
|--------|--------------------------------------|--|------------------------|-----|-----|------|
| Symbol | Characteristic | Condition | Min | Тур | Max | Unit |
| VOLP | Dynamic LOW Peak Voltage (Note 4.) | $V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$ | | 0.8 | | V |
| VOLV | Dynamic LOW Valley Voltage (Note 4.) | $V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$ | | 0.8 | | V |

^{4.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

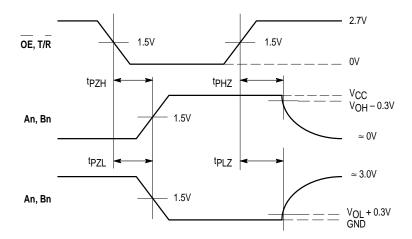
CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Condition | Typical | Unit |
|------------------|-------------------------------|---|---------|------|
| C _{IN} | Input Capacitance | $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} | 7 | pF |
| C _{I/O} | Input/Output Capacitance | $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10MHz, $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} | 25 | pF |



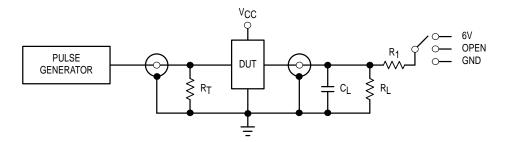
WAVEFORM 1 - PROPAGATION DELAYS

 t_R = t_F = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5 ns, \ 10\% \ to \ 90\%; \ f = 1 MHz; \ t_W = 500 ns$

Figure 1. AC Waveforms

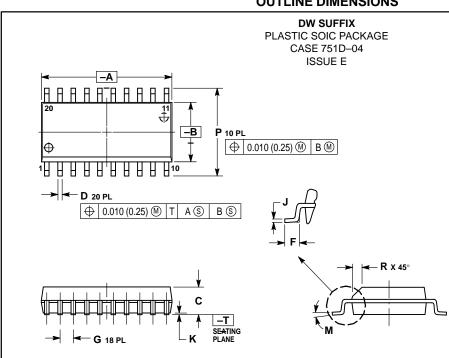


| TEST | SWITCH |
|-------------------------------------|--------|
| t _{PLH} , t _{PHL} | Open |
| tPZL, tPLZ | 6V |
| Open Collector/Drain tpLH and tpHL | 6V |
| ^t PZH ^{, t} PHZ | GND |

 C_L = 50pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 2. Test Circuit

OUTLINE DIMENSIONS



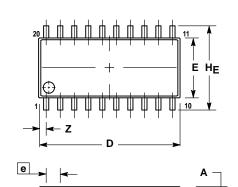
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

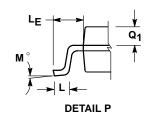
| | MILLIMETERS | | INC | HES |
|-----|-------------|-------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 12.65 | 12.95 | 0.499 | 0.510 |
| В | 7.40 | 7.60 | 0.292 | 0.299 |
| С | 2.35 | 2.65 | 0.093 | 0.104 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.50 | 0.90 | 0.020 | 0.035 |
| G | 1.27 | BSC | 0.050 | BSC |
| J | 0.25 | 0.32 | 0.010 | 0.012 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| М | 0° | 7° | 0° | 7° |
| Р | 10.05 | 10.55 | 0.395 | 0.415 |
| R | 0.25 | 0.75 | 0.010 | 0.029 |

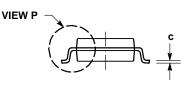
M SUFFIX PLASTIC SOIC EIAJ PACKAGE

CASE 967-01 ISSUE O



⊕ 0.13 (0.005) M





6

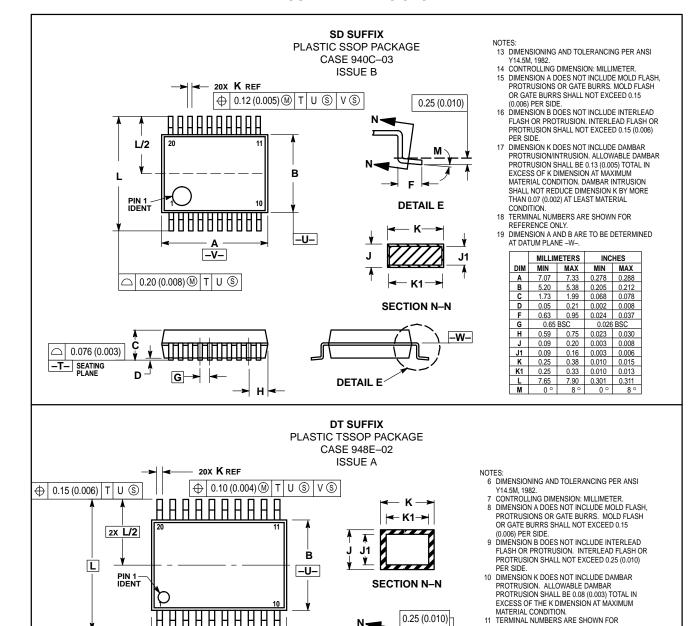
- NOTES:
 1 DIMENSIONING AND TOLERANCING PER ANSI
- 1 DIMENSIONING AND TOLEKANCING PER ANSI Y14.5M, 1982. 2 CONTROLLING DIMENSION: MILLIMETER. 3 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) DED SIDE. PER SIDE
- 4 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 5 THE LEAD WIDTH DIMENSION (b) DOES NOT
- INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.
 DAMBAR CANNOT BE LOCATED ON THE LOWER
 RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| | MILLIMETERS INC | | | HES |
|----------------|-----------------|-------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | | 2.05 | | 0.081 |
| Α ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| С | 0.18 | 0.27 | 0.007 | 0.011 |
| D | 12.35 | 12.80 | 0.486 | 0.504 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| е | 1.27 | BSC | 0.050 | BSC |
| HE | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| LE | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0 ° | 10° | 0 ° | 10 ° |
| Q_1 | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | | 0.81 | | 0.032 |

MOTOROLA

0.10 (0.004)

OUTLINE DIMENSIONS



0.25 (0.010)

DETAIL E

DETAIL E

-W-

Н

<u>0.100 (0.004)</u> -T- SEATING

-V-

⊕ 0.15 (0.006) T U ⑤

Н

MILLIMETERS INCHES DIM MIN MAX MIN MAX 0.252 0.260 6.60 Α 6.40 4.50 1.20 0.169 0.177 --- 0.047 B C 4.30 0.002 0.006 0.020 0.030 0.15 0.75 D F 0.05 0.50 G H 0.65 BSC 0.27 0.37 3SC 0.026 BSC 0.37 0.011 0.015 0.20 0.004 0.008 J J1 0.09 0.09 | 0.16 | 0.004 | 0.006 K K1 0.19 0.30 0.007 0.012 0.25 0.007 0.010 6.40 BSC 0.252 BSC 0° 8

REFERENCE ONLY.

12 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

MC74LCX245

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